ABSOLUTE MAXIMUM RATINGS

(All Voltages Referenced to GND, Unless	s Otherwise Noted.)
V+, IN	0.3V to +6.0V
COM_, NO_, NC_ (Note 1)	0.3V to $(V + + 0.3V)$
Continuous Current COM_, NO_, NC	±100mA
Peak Current COM_, NO_, NC_	
(pulsed at 1ms, 10% duty cycle)	±200mA
Continuous Power Dissipation ($T_A = +70$	л°С)
8-Pin µMAX (derate 4.5mW/°C above 9-Bump UCSP (derate 4.7mW/°C above	,

ESD Method 3015.7	>2kV
Operating Temperature Range	40°C to +85°C
Junction Temperature	+150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C
Bump Temperature (soldering) (Note 2)	
Infrared (15s)	+220°C
Vapor Phase (60s)	+215°C

- Note 1: Signals on COM_, NO_, or NC_ exceeding V+ or GND are clamped by internal diodes. Limit forward-diode current to maximum current rating.
- Note 2: This device is constructed using a unique set of packaging techniques that impose a limit on the thermal profile the device can be exposed to during board level solder attach and rework. This limit permits only the use of the solder profiles recommended in the industry standard specification, JEDEC 020A, paragraph 7.6, table 3 for IR/VPR and convection reflow. Preheating is required. Hand or wave soldering is not allowed.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—Single +3V Supply

 $(V+ = +2.7V \text{ to } +3.6V, V_{IH} = +1.4V, V_{IL} = +0.5V, T_A = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted. Typical values are at } V+ = +3.0V, T_A = +25^{\circ}C, \text{ unless otherwise noted.})$ (Notes 3, 4)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS		
Analog Signal Range	V _{COM_} , V _{NO_} , V _{NC_}			0		V+	V		
ANALOG SWITCH									
		V. 0.7V. 1. 10m. A.	+25°C		3.0	4.5			
On-Resistance (Note 5)	RON	V+ = 2.7V, I _{COM} = 10mA; V _{NO} or V _{NC} = 1.5V	T _{MIN} to T _{MAX}			5	Ω		
On Desistance Matala Batusan		V 0.7V L 10mA	+25°C		0.1	0.3			
On-Resistance Match Between Channels (Notes 5, 6)	ΔR _{ON}	V+ = 2.7V, I _{COM} = 10mA; V _{NO} or V _{NC} = 1.5V	T _{MIN} to T _{MAX}			0.4	Ω		
			+25°C		0.6	1.2			
On-Resistance Flatness (Note 7)	R _{FL} AT(ON)	V+ = 2.7V, I _{COM} = 10mA; V _{NO} or V _{NC} = 1.0V, 1.5V, 2.0V	T _{MIN} to T _{MAX}			1.5	Ω		
No No off L	I _{NO_(OFF)} , I _{NC_(OFF)}		+25°C	-0.5	+0.01	+0.5			
NO_, NC_ Off-Leakage Current (Note 8)		$V+ = 3.6V, V_{COM} = 0.3V, 3.3V;$ V_{NO} or $V_{NC} = 3.3V, 0.3V$	T _{MIN} to T _{MAX}	-1.5		+1.5	nA		
0011 0" 0			+25°C	-0.5	+0.01	+0.5			
COM_ Off-Leakage Current (Note 8)	_ 、 , ,	V+ = 3.6V, V _{COM} _ = 0.3V, 3.3V; V _{NO} _ or V _{NC} _ = 3.3V, 0.3V	T _{MIN} to T _{MAX}	-1.5		+1.5	nA		
		$V + = 3.6V, V_{COM} = 0.3V, 3.3V;$	+25°C	-1	+0.01	+1			
COM_ On-Leakage Current (Note 8)	ICOM_(ON)	V_{NO} or V_{NC} = 0.3V, 3.3V, or floating	T _{MIN} to T _{MAX}	-2		+2	nA		
			+25°C		40	80			
Turn-On Time	ton	$V_{NO_}$, $V_{NC_}$ = 1.5V; R_L = 300 Ω , C_L = 35pF, Figure 1	T _{MIN} to T _{MAX}			100	ns		

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ELECTRICAL CHARACTERISTICS—Single +3V Supply (continued)

 $(V+=+2.7V \text{ to } +3.6V, V_{IH}=+1.4V, V_{IL}=+0.5V, T_A=T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted.}$ Typical values are at V+ = +3.0V, T_A=+25°C, unless otherwise noted.) (Notes 3, 4)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS
DYNAMIC CHARACTERISTICS	•						
		\\ \\ 4.5\\.	+25°C		20	40	
Turn-Off Time	toff	$V_{NO_}$, $V_{NC_}$ = 1.5V; R_L = 300 Ω , C_L = 35pF, Figure 1	T _{MIN} to T _{MAX}	5		50	ns
Dural Dafara Mala Tima Dalar		V V	+25°C		8		
Break-Before-Make Time Delay (MAX4723 Only) (Note 8)	t _{BBM}	$V_{NO_}$, $V_{NC_}$ = 1.5V; R_L = 300 Ω , C_L = 35pF, Figure 2	T _{MIN} to T _{MAX}	1			ns
Skew (Note 8)	tskew	$R_S = 39\Omega$, $C_L = 50pF$, Figure 3	T _{MIN} to T _{MAX}		0.15	0.2	ns
Charge Injection	Q	$V_{GEN} = 2V$, $R_{GEN} = 0\Omega$, $C_L = 1.0$ nF, Figure 4	+25°C		5		рС
Off location (Note 0)	Vice	$f = 10MHz; V_{NO}, V_{NC} = 1V_{P-P};$ $R_L = 50\Omega, C_L = 5pF, Figure 5a$. 25%		-55		٩D
Off-Isolation (Note 9)	V _{ISO}	$f = 1MHz; V_{NO}, V_{NC} = 1V_{P-P};$ $R_L = 50\Omega, C_L = 5pF, Figure 5a$	+25°C	-80			dB
Crosstalk (Note 10)		$f = 10MHz; V_{NO}, V_{NC} = 1V_{P-P}; R_L = 50\Omega, C_L = 5pF, Figure 5b$	= 5pF, Figure 5b		-80		
	VCT	$f = 1MHz; V_{NO_}, V_{NC_} = 1V_{P-P};$ $R_L = 50\Omega, C_L = 5pF, Figure 5b$	+25°C		-110		dB
On-Channel -3dB Bandwidth	BW	Signal = 0dBm, C_L = 5pF, R_L = 50 Ω , Figure 5a	+25°C	>300			MHz
Total Harmonic Distortion	THD	$R_L = 600\Omega$	+25°C		0.03		%
NO_, NC_ Off-Capacitance	C _{NO_} (OFF) C _{NC_} (OFF)	f = 1MHz, Figure 6	+25°C		9		pF
Switch On-Capacitance	C _(ON)	f = 1MHz, Figure 6	+25°C		15		рF
DIGITAL I/O	1		T	T			_
Input Logic High Voltage	VIH		T _{MIN} to T _{MAX}	1.4			V
Input Logic Low Voltage	VIL	T _{MIN} to T _{MAX}		0.5	V		
Input Leakage Current	I _{IN}	V+ = +3.6V, V _{IN} _ = 0 or 5.5V	T _{MIN} to T _{MAX}	-0.1		+0.1	μΑ
SUPPLY							
Supply Voltage Range	V+	T _{MIN} to T _{MAX} 1.8		5.5	V		
Positive Supply Current	l+	$V+ = 5.5V$, $V_{IN} = 0V$ or $V+$ $T_{MIN} \text{ to}$ T_{MAX}		1	μA		



ELECTRICAL CHARACTERISTICS—Single +5V Supply

 $(V+=+4.2V \text{ to } +5.5V, V_{IH}=+2.0V, V_{IL}=+0.8V, T_A=T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted. Typical values are at } V+=+5.0V, T_A=+25^{\circ}C, \text{ unless otherwise noted.)}$ (Notes 3, 4)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS	
Analog Signal Range	V _{COM_} , V _{NO_} , V _{NC_}		T _{MIN} to T _{MAX}	0		V+	V	
ANALOG SWITCH								
		VI = 4.2V look = 10mA:	+25°C		1.7	3.0		
On-Resistance (Note 5)	Ron	V+ = 4.2V, I _{COM} = 10mA; V _{NO} or V _{NC} = 3.5V	T _{MIN} to			3.5	Ω	
On Desistance Match Datum		V 4.0V L 40A	+25°C		0.1	0.3		
On-Resistance Match Between Channels (Notes 5, 6)	ΔR _{ON}	V+ = 4.2V, I _{COM} = 10mA; V _{NO} or V _{NC} = 3.5V	T _{MIN} to			0.4	Ω	
		V 4.0V L 40~A	+25°C		0.4	1.2		
On-Resistance Flatness (Note 7)	R _{FLAT} (ON)	V+ = 4.2V, I _{COM} = 10mA; V _{NO} or V _{NC} = 1.0V, 2.0V, 3.5V	T _{MIN} to T _{MAX}			1.5	Ω	
NO NO 011 1 0 1		V 55V V 45V	+25°C	-0.5	+0.01	+0.5		
NO_, NC_ Off-Leakage Current (Note 8)	INO_(OFF), INC_(OFF)	V+ = 5.5V, V _{COM} _ = 1.0V, 4.5V; V _{NO} _ or V _{NC} _ = 4.5V, 1.0V	T _{MIN} to	-1.5		+1.5	nA	
0014 0"1 1 0 1		V+ = 5.5V, V _{COM} _ = 1V, 4.5V; V _{NO} _ or V _{NC} _ = 4.5V, 1V	+25°C	-0.5	+0.01	+0.5	nA	
COM _ Off-Leakage Current (Note 8)	ICOM_(OFF)		T _{MIN} to	-1.5		+1.5		
		$V + = 5.5V, V_{COM} = 1.0V, 4.5V;$	+25°C	-1	+0.01	+1		
COM_ On-Leakage Current (Note 8)	ICOM_(ON)	V_{NO} or V_{NC} = 1.0V, 4.5V, or floating	T _{MIN} to T _{MAX}	-2		+2	nA	
DYNAMIC CHARACTERISTICS	•							
			+25°C		30	80	ns	
Turn-On Time	ton	$V_{NO_}$, $V_{NC_}$ = 3.0V; R_L = 300 Ω , C_L = 35pF, Figure 1	T _{MIN} to			90		
		V V 20V	+25°C		20	40		
Turn-Off Time	me $ \begin{array}{c c} t_{OFF} & V_{NO_}, V_{NC_} = 3.0V; \\ R_L = 300\Omega, C_L = 35pF \end{array} $		T _{MIN} to T _{MAX}			50	ns	
D I D (M I T D I			+25°C		8			
Break-Before-Make Time Delay (MAX4723 Only) (Note 8)	tBBM	$V_{NO_}$, $V_{NC_}$ = 3.0V; R_L = 300 Ω , C_L = 35pF, Figure 2	T _{MIN} to	1			ns	
Skew (Note 8)	tskew	$R_S = 39\Omega$, $C_L = 50pF$, Figure 3	T _{MIN} to T _{MAX}		1.5	2	ns	
DIGITAL I/O								
Input Logic High Voltage	VIH		T _{MIN} to T _{MAX}	2.0			V	
Input Logic Low Voltage	V _{IL}		T _{MIN} to T _{MAX}			0.8	٧	

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ELECTRICAL CHARACTERISTICS—Single +5V Supply (continued)

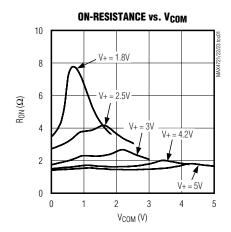
 $(V+ = +4.2V \text{ to } +5.5V, V_{IH} = +2.0V, V_{IL} = +0.8V, T_A = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted.}$ Typical values are at $V+ = +5.0V, T_A = +25^{\circ}C$, unless otherwise noted.) (Notes 3, 4)

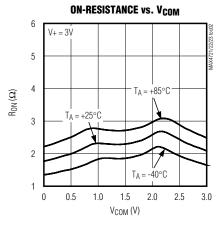
PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS		
Input Leakage Current	IIN	I_{IN} $V+ = 5.5V$, $V_{IN} = 0V$ or $V+$ T_{MIN} to T_{MAX}		-0.1		+0.1	μΑ		
POWER SUPPLY									
Power-Supply Range	V+		T _{MIN} to	1.8		5.5	V		
Positive Supply Current	l+	V+ = 5.5V, V _{IN} _ = 0V or V+	T _{MIN} to T _{MAX}			1	μΑ		

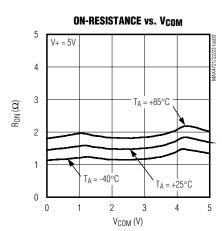
- **Note 3:** UCSP parts are 100% tested at +25°C only, and guaranteed by design over the specified temperature range. μMAX parts are 100% tested at T_{MAX} and guaranteed by design over the specified temperature range.
- **Note 4:** The algebraic convention used in this data sheet is where the most negative value is a minimum and the most positive value is a maximum.
- Note 5: Guaranteed by design for UCSP parts.
- **Note 6:** $\Delta R_{ON} = R_{ON(MAX)} R_{ON(MIN)}$.
- **Note 7:** Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal ranges.
- Note 8: Guaranteed by design.
- **Note 9:** Off-Isolation = $20log_{10}$ (V_{COM} / V_{NO}), V_{COM} = output, V_{NO} = input to off switch.
- Note 10: Between any two switches.

Typical Operating Characteristics

 $(T_A = +25^{\circ}C, \text{ unless otherwise noted.})$



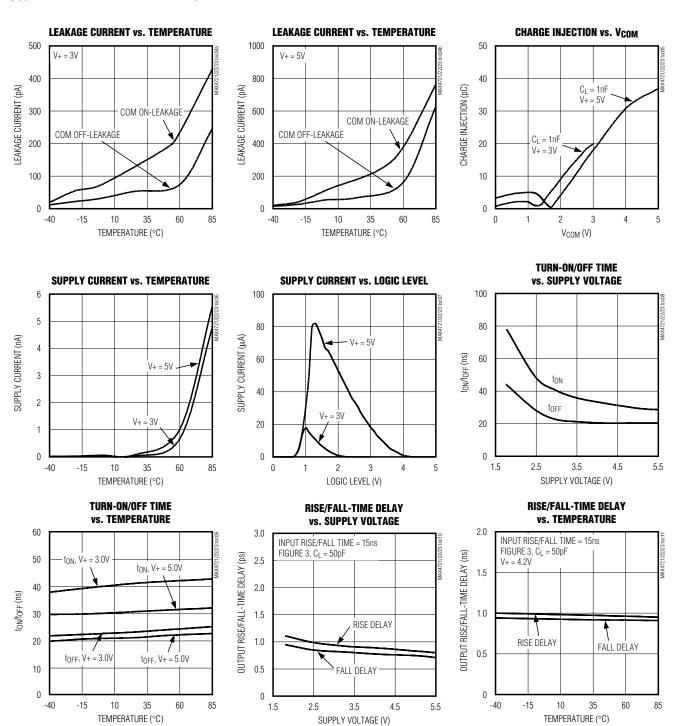




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Typical Operating Characteristics (continued)

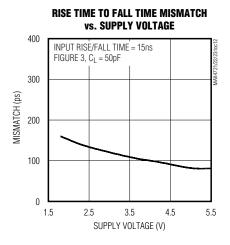
 $(T_A = +25$ °C, unless otherwise noted.)

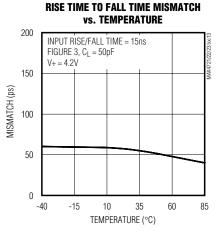


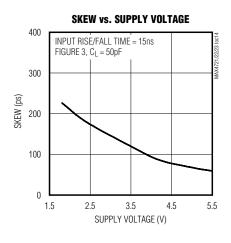
6 ______ /N/XI/M

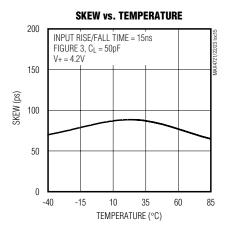
Typical Operating Characteristics (continued)

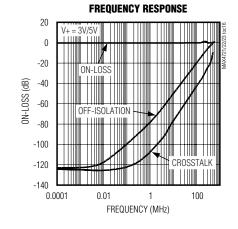
 $(T_A = +25$ °C, unless otherwise noted.)

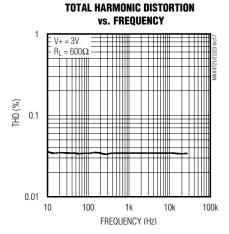


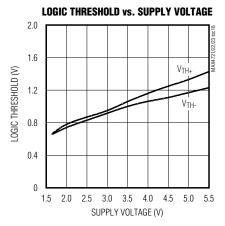












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Pin Description

		P	IN				
MAX	MAX4721		4722	MAX4723		NAME	FUNCTION
UCSP	μМΑХ	UCSP	μМΑХ	UCSP	μMAX		
A1	3	A1	3	A1	3	IN2	Logic-Control Digital Input
A2	4	A2	4	A2	4	GND	Ground. Connect to digital ground.
АЗ	5	_	_	_	_	NO2	Analog-Switch Normally Open Terminal
B1	2	B1	2	B1	2	COM1	Analog-Switch Common Terminal
В3	6	В3	6	В3	6	COM2	Analog-Switch Common Terminal
C1	1	_	_	C1	1	NO1	Analog-Switch Normally Open Terminal
C2	8	C2	8	C2	8	V+	Positive Analog Supply
C3	7	C3	7	C3	7	IN1	Logic-Control Digital Input
_	_	C1	1	_	_	NC1	Analog-Switch Normally Closed Terminal
_	_	А3	5	А3	5	NC2	Analog-Switch Normally Closed Terminal

Detailed Description

The MAX4721/MAX4722/MAX4723 dual SPST analog switches operate from a single +1.8V to +5.5V supply. The MAX4721/MAX4722/MAX4723 offer excellent AC characteristics, <0.5nA leakage current, less than 2ms differential skew, and 15pF on-channel capacitance. All of these devices are CMOS-logic compatible with rail-to-rail signal handling capability.

The MAX4721/MAX4722/MAX4723 are USB-compliant switches that provide 4.5 Ω (max) on-resistance, and 15pF on-channel capacitance to maintain signal integrity. At 12Mbps (USB full-speed data rate specification) the MAX4721/MAX4722/MAX4723 introduce less than 2ns propagation delay between input and output signals and less than 0.5ns change in skew for the output signals (see Figure 3 for more details).

The MAX4721 has two normally open (NO) switches, the MAX4722 has two normally closed (NC) switches, and the MAX4723 has one NO switch and one NC switch.

Applications Information

Digital Control Inputs

The MAX4721/MAX4722/MAX4723 logic inputs accept up to +5.5V regardless of supply voltage. For example, with a +3.3V supply, IN_ can be driven low to GND and high to +5.5V allowing for mixing of logic levels in a system. Driving the control logic inputs rail-to-rail minimizes power consumption. For a +3.0V supply voltage, the logic thresholds are 0.5V (low) and 1.4V (high); for a +5V supply voltage, the logic thresholds are 0.8V (low) and 2.0V (high).

Analog Signal Levels

Analog signals that range over the entire supply voltage (V+ to GND) are passed with very little change in on-resistance (see the *Typical Operating Characteristics*). The switches are bidirectional, so the NO_, NC_, and COM_pins can be either inputs or outputs.

Test Circuits/Timing Diagrams

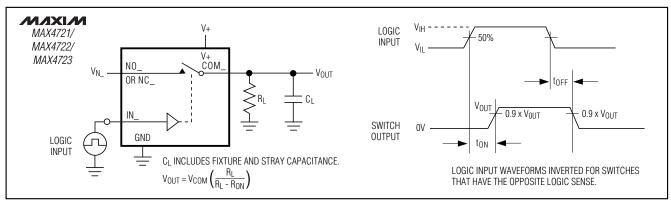


Figure 1. Switching Time

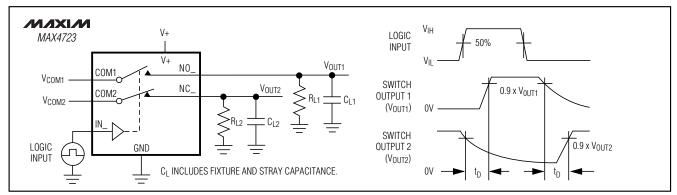


Figure 2. Break-Before-Make Interval

Power-Supply Bypassing

Power-supply bypassing improves noise margin and prevents switching noise from propagating from the V+ supply to other components. A $0.1\mu F$ capacitor connected from V+ to GND is adequate for most applications.

Power-Supply Sequencing and Overvoltage Protection

Caution: Do not exceed the absolute maximum ratings because stresses beyond the listed ratings may cause permanent damage to the device.

UCSP Package Considerations

For general UCSP package information and PC layout considerations, please refer to the Maxim Application Note (Wafer-Level Chip-Scale Package).

UCSP Reliability

The chip-scale package (UCSP) represents a unique packaging form factor that may not perform equally to a packaged product through traditional mechanical reliability tests. UCSP reliability is integrally linked to the user's assembly methods, circuit board material, and usage environment. The user should closely review these areas when considering use of a UCSP package. Performance through Operating Life Test and Moisture Resistance remains uncompromised as it is primarily determined by the wafer-fabrication process.

Mechanical stress performance is a greater consideration for a UCSP package. UCSPs are attached through direct solder contact to the user's PC board, foregoing the inherent stress relief of a packaged product lead frame. Solder joint contact integrity must be considered. Information on Maxim's qualification plan, test data, and recommendations are detailed in the UCSP application note, which can be found on Maxim's website at www.maxim-ic.com.



Test Circuits/Timing Diagrams (continued)

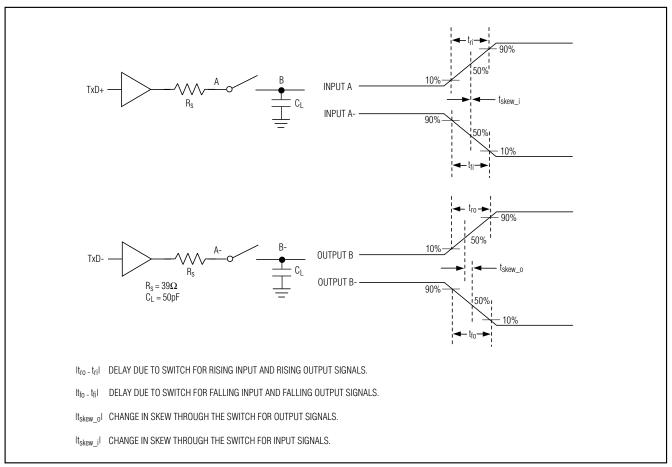


Figure 3. Input/Output Skew Timing Diagram

Test Circuits/Timing Diagrams (continued)

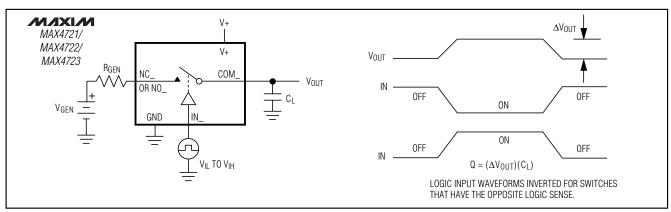


Figure 4. Charge Injection

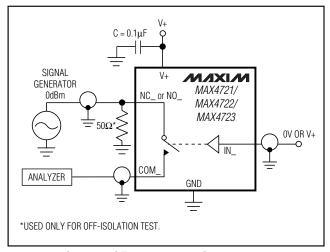


Figure 5a. On-Loss, Off-Isolation, and Crosstalk

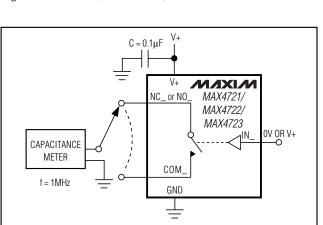


Figure 6. Channel Off/On-Capacitance

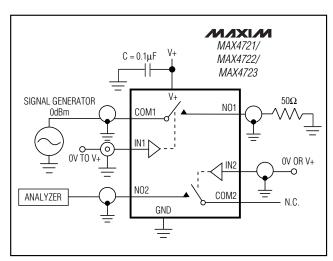


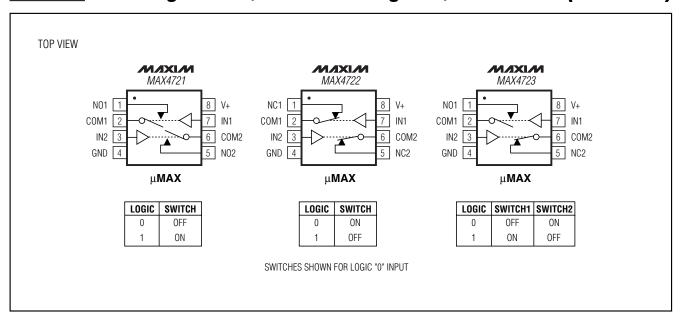
Figure 5b. Crosstalk Test Circuit

Chip Information

TRANSISTOR COUNT: 181
PROCESS: BiCMOS

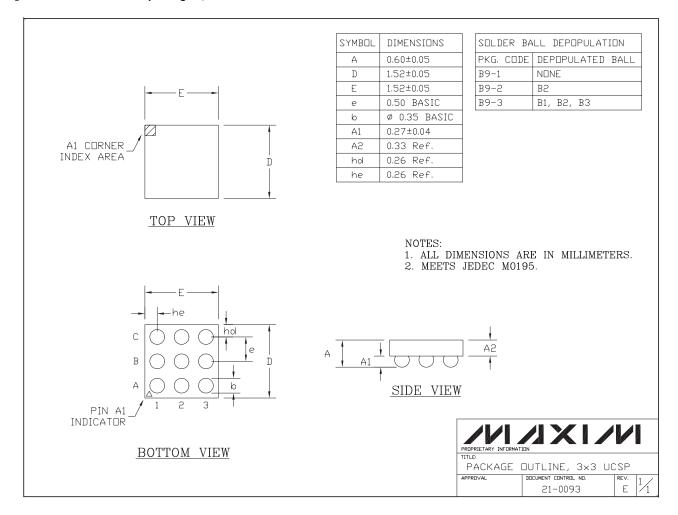


Pin Configurations/Functional Diagrams/Truth Tables (continued)



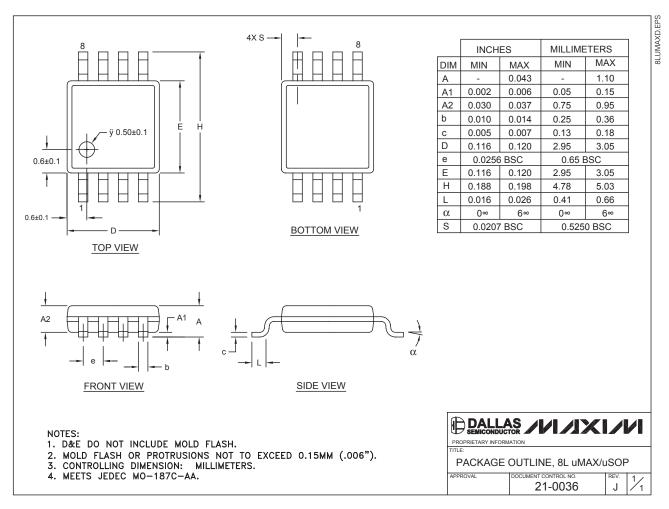
Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to **www.maxim-ic.com/packages**.)



Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to **www.maxim-ic.com/packages**.)



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